



DESCRIPTION:

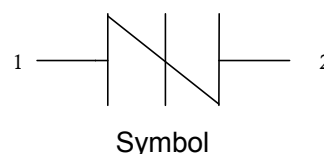
PxxxxSB series thyristors are a type of semi-conduct component. They are designed to protect baseband equipment from damaging overvoltage transients. such as modems, telephones, line cards, answering machines, FAX machines, T1/E1, xDSL and more.



SMB

FEATURES:

- ✧ Excellent capability of absorbing transient surge
- ✧ Quick response to surge voltage (ns Level)
- ✧ Eliminates overvoltage caused by fast rising transients
- ✧ Moisture sensitivity level: Level 1
- ✧ Non degenerative

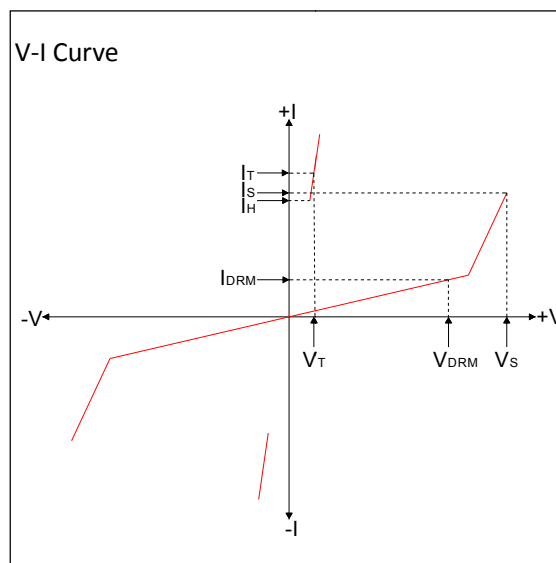


ABSOLUTE MAXIMUM RATINGS (T_A=25°C, RH=45%-75%, unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|--------------------------------------|------------------|-------------|------|
| Storage temperature range | T _{stg} | -60 to +150 | °C |
| Operating junction temperature range | T _j | -40 to +125 | °C |
| Repetitive peak pulse current | I _{PP} | 80 | A |

ELECTRICAL CHARACTERISTICS (T_A=25°C)

| Symbol | Parameter |
|------------------|------------------------|
| V _{DRM} | Peak off-state voltage |
| I _{DRM} | Off-state current |
| V _S | Switching voltage |
| I _S | Switching current |
| V _T | On-state voltage |
| I _T | On-state current |
| I _H | Holding current |
| C _O | Off-state capacitance |



ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$, continued)

| Part Number | $I_{\text{DRM}}@V_{\text{DRM}}$ | | $V_S^{\text{①}}@I_S$ | | $V_T@I_T$ | | I_H | $C_O^{\text{②}}$ | Marking |
|-------------|---------------------------------|-----|----------------------|-----|-----------|-----|-------|------------------|---------|
| | μA | V | V | mA | V | A | mA | pF | |
| | max | | max | max | max | max | min | max | |
| P0080SB | 5 | 6 | 25 | 800 | 4 | 2.2 | 30 | 130 | P-8B |
| P0220SB | 5 | 18 | 30 | 800 | 4 | 2.2 | 30 | 120 | P22B |
| P0300SB | 5 | 25 | 40 | 800 | 4 | 2.2 | 30 | 120 | P03B |
| P0640SB | 5 | 58 | 77 | 800 | 4 | 2.2 | 120 | 80 | P06B |
| P0720SB | 5 | 66 | 87 | 800 | 4 | 2.2 | 120 | 75 | P07B |
| P0900SB | 5 | 75 | 98 | 800 | 4 | 2.2 | 120 | 70 | P09B |
| P1100SB | 5 | 90 | 130 | 800 | 4 | 2.2 | 120 | 70 | P11B |
| P1300SB | 5 | 120 | 160 | 800 | 4 | 2.2 | 120 | 60 | P13B |
| P1500SB | 5 | 140 | 180 | 800 | 4 | 2.2 | 120 | 55 | P15B |
| P1800SB | 5 | 170 | 220 | 800 | 4 | 2.2 | 120 | 50 | P18B |
| P2300SB | 5 | 190 | 260 | 800 | 4 | 2.2 | 120 | 50 | P23B |
| P2600SB | 5 | 220 | 300 | 800 | 4 | 2.2 | 120 | 45 | P26B |
| P3100SB | 5 | 275 | 350 | 800 | 4 | 2.2 | 120 | 45 | P31B |
| P3500SB | 5 | 320 | 400 | 800 | 4 | 2.2 | 120 | 40 | P35B |
| P3800SB | 5 | 340 | 450 | 800 | 4 | 2.2 | 120 | 40 | P38B |

① V_S is measured at 100KV/s

② Off-state capacitance is measured in $V_{\text{DC}}=2\text{V}$, $V_{\text{RMS}}=1\text{V}$, $f=1\text{MHz}$

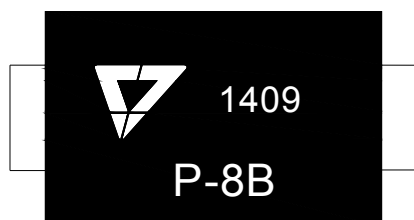
SURGE RATINGS

| Series | $I_{\text{PP}}(\text{A})$ min | | | |
|--------|-------------------------------|--------|----------|-----------|
| | 2×10us | 8×20us | 10×360us | 10×1000us |
| B | 250 | 250 | 125 | 80 |

ORDERING INFORMATION

| | | | | |
|--|---|---|----------|----------|
| P Series code P: SIDACTor Median voltage | 008 Surge ratings:4KV(10/700us) | 0 Package type 0: Bi-direction 1: Uni-direction | S | B |
|--|---|---|----------|----------|

MARKING



P-8B : Device Marking Code
 1409: In ninth week, 2014

SOLDERING PARAMETERS

| | | |
|---|-----------------------------------|---------------------------------|
| Reflow Condition | | Pb-Free assembly (see FIG.2) |
| Pre Heat | -Temperature Min ($T_{s(min)}$) | +150°C |
| | -Temperature Max($T_{s(max)}$) | +200°C |
| | -Time (Min to Max) (ts) | 60-180 secs. |
| Average ramp up rate (Liquid us Temp (T_L) to peak) | | 3°C/sec. Max |
| $T_{s(max)}$ to T_L - Ramp-up Rate | | 3°C/sec. Max |
| Reflow | -Temperature(T_L) (Liquid us) | +217°C |
| | -Temperature(t_L) | 60-150 secs. |
| Peak Temp (T_p) | | +260(+0/-5)°C |
| Time within 5°C of actual Peak Temp (t_p) | | 30 secs. Max |
| Ramp-down Rate | | 6°C/sec. Max |
| Time 25°C to Peak Temp (T_P) | | 8 min. Max |
| Do not exceed | | +260°C |

FIG.1: $t_r \times t_d$ pulse waveform

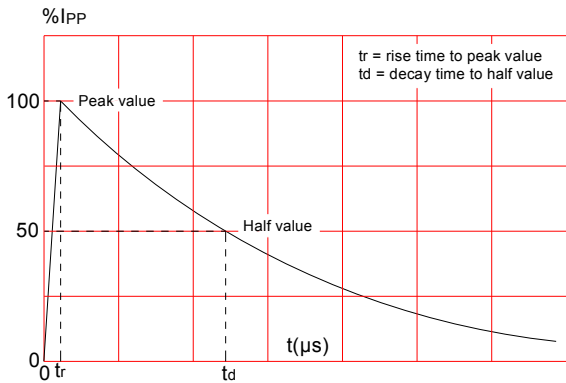


FIG.3: Normalized V_s change vs. junction temperature

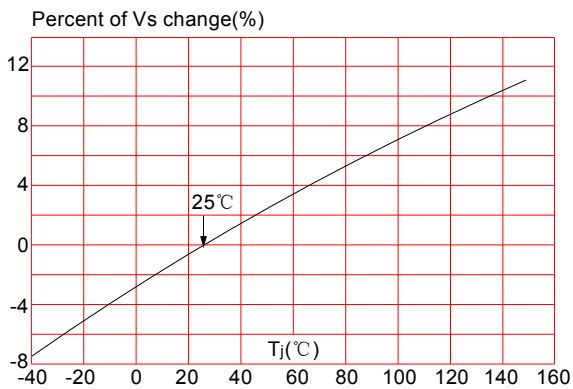


FIG.2: Reflow condition

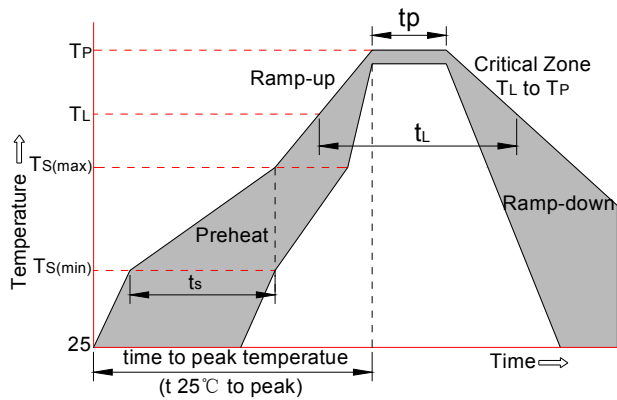
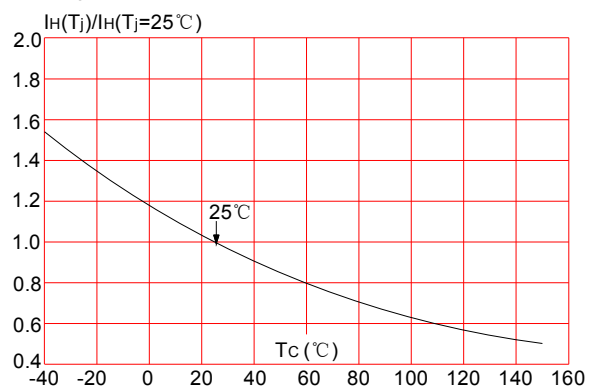
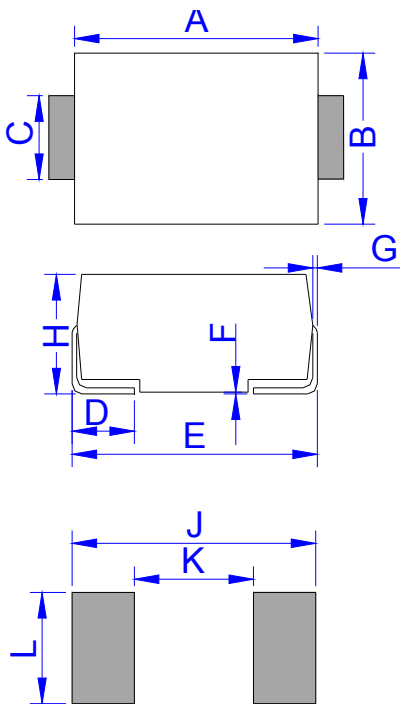


FIG.4: Normalized DC holding current vs. case temperature



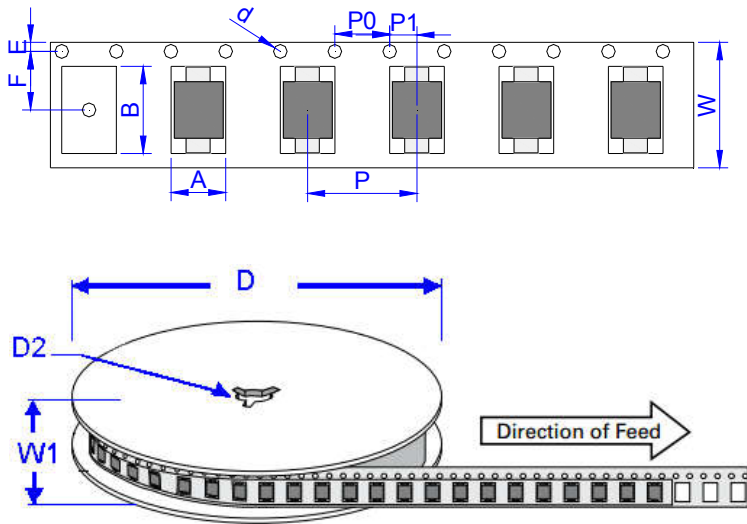
PACKAGE MECHANICAL DATA



DO-214AA (SMB)

| Ref. | Dimensions | | | |
|------|-------------|-------|--------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 4.25 | 4.75 | 0.167 | 0.187 |
| B | 3.30 | 3.94 | 0.130 | 0.155 |
| C | 1.85 | 2.21 | 0.073 | 0.087 |
| D | 0.76 | 1.52 | 0.030 | 0.060 |
| E | 5.08 | 5.59 | 0.200 | 0.220 |
| F | 0.051 | 0.203 | 0.002 | 0.008 |
| G | 0.15 | 0.31 | 0.006 | 0.012 |
| H | 2.11 | 2.44 | 0.083 | 0.096 |
| J | 6.80 | | 0.270 | |
| K | | 2.60 | | 0.100 |
| L | 2.40 | | 0.090 | |

TAPE AND REEL SPECIFICATION-SMB



| Ref. | Dimensions | |
|------|-------------|---------------|
| | Millimeters | Inches |
| A | 3.76 ± 0.2 | 0.144 ± 0.012 |
| B | 5.69 ± 0.2 | 0.244 ± 0.012 |
| d | 1.5 ± 0.25 | 0.059 ± 0.004 |
| D | 330.0 | 13.0 |
| D2 | 13 ± 1 | 0.512 ± 0.039 |
| E | 1.75 ± 0.2 | 0.059 ± 0.008 |
| F | 5.5 ± 0.1 | 0.222 ± 0.008 |
| P | 8.0 ± 0.2 | 0.315 ± 0.008 |
| P0 | 4.0 ± 0.2 | 0.157 ± 0.008 |
| P1 | 2.0 ± 0.2 | 0.079 ± 0.008 |
| W | 12.0 ± 0.3 | 0.472 ± 0.008 |
| W1 | 16.8 ± 2.0 | 0.661 ± 0.079 |

| OUTLINE | REEL (PCS) | PER CARTON (PCS) | REEL DIAMETERS (mm) |
|---------|------------|------------------|---------------------|
| TAPING | 3,000 | 48,000 | 330 |

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